TYPES 2N512, 2N512A, 2N512B

DL-S 1051

MARCH, 1959

P-N-P ALLOY - JUNCTION GERMANIUM POWER TRANSISTORS

40, 60, 80 VOLTS 15-AMP COLLECTOR CURRENT 80-WATT DISSIPATION — 0.05 OHM MAX R_{cs} LOW I_{co} LOW V_{BE}

for

AUDIO AMPLIFIERS — SWITCHING CIRCUITS



ACTUAL SIZE

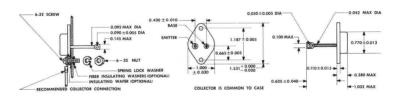
qualification testing

All units are subjected to a high-pressure leak test and are heat cycled from -55° C and room humidity to $+95^{\circ}$ C and 95% relative humidity, for four complete cycles over an eight-hour period. In addition, all units are stored at $+95^{\circ}$ C for 100 hours and then thoroughly tested for rigid adherence to electrical design characteristics.

mechanical

The use of high-temperature silver solder to assemble the mounting base and the use of projection welds to seal the can, provide a hermetically-sealed enclosure which can withstand up to 300 psi. During the assembly process, the absence of flux, soft solder, and wet processing combined with extra cleanliness, prevents sealed-in contamination.

The mounting base is a high conductivity copper which provides an excellent heat path from the collector junction to a heat sink which must be tightly attached to permit operation at maximum rated dissipation. The approximate weight of the unit is 23 grams.



maximum	rati	ngs	at	25	,C*
---------	------	-----	----	----	-----

irings at 25°C*		2N512	2N512A	2N512B	unit
V _{CBO}	Collector-to-Base Voltage (I _C = -5ma, I _E = 0)	-40	-60	-80	٧
VCEX	Collector-to-Emitter Voltage ($V_{BE} = +0.2 \text{ v}, I_{C} = -5 \text{ma}$)	-40	60	-80	٧
VEBO	Emitter-to-Base Voltage ($I_E = -5$ ma, $I_C = 0$)	-30	-30	-30	V
l _C	DC Collector Current	— 15	-15	15	а
I _E	DC Emitter Current	-15	-15	— 15	а
I _B	Base Current	-5	5	-5	a
	Total Dissipation†	80	80	80	w
T	Junction Temperature	95	95	95	°C

typical characteristics at 25°C*

h _{FE}	Forward Current Transfer Ratio $(V_{CE} = -1.5 \text{ v}, I_C = -3.7 \text{ a})$ $(V_{CE} = -1.5 \text{ v}, I_C = -15 \text{ a})$	30 12	30 12	30 12	
Rcs	Common Emitter Saturation Resistance ($I_C = -15a$, $I_B = -2.25a$)	0.025	0.025	0.025	ohm
К	Thermal Resistance from Collector Junction to Mounting Base	0.7	0.7	0.7	°C/w
BV _{CES}	Collector to Emitter Breakdown Voltage with Base Shorted to Emitter ($I_C = -300 \text{ma}_v V_{BE} = 0$)	— 55	—65	—75	V
BVCEO	Collector to Emitter Breakdown Voltage ($I_C = -300$ ma, $I_B = 0$)	—40	—50	60	V
I _{CBO}	Collector Reverse Current (V _{CB} = ½ V _{CBO} max, T _J = 85°C)	-8.0	-8.0	-8.0	ma

^{*} Temperature is measured on mounting base.

SEMICONDUCTOR—COMPONENTS DIVISION

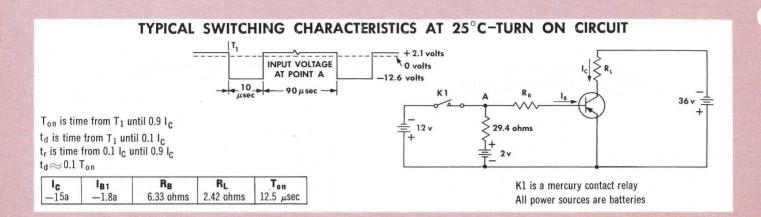
LICENSED UNDER BELL SYSTEM PATENTS

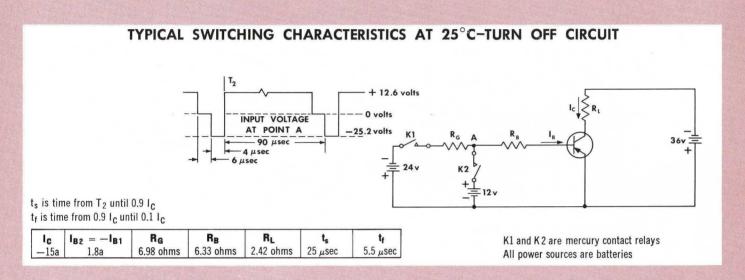
SEMICONDUCTOR COMPONENTS DIVISION
POST OFFICE BOX 312 . 13500 N. CENTRAL EXPRESSWAY

[†] For operation at higher temperatures refer to derating curve.

TYPES 2N512, 2N512A, 2N512B

TYPICAL CHARACTERISTICS AND APPLICATION NOTES





L5 may be wound according to the output voltage desired, allowing about turns per volt. The wire size should be large enough to allow one circular mil per millampere. The output current and load will then determine D4, D5, D6, D_7 and C4.

L2, L3—29 turns each bifilar wound #12

L1, L4-10 turns each 318 #18

Q1, Q2—2N512 15 amp 40 volt each mounted on a total of 150 sq. in. exposed surface of $\frac{1}{8}$ " aluminum sheet. Operation to 60° C.

D1, D2, D3-1N2069

 $R1 = 1 \text{ K} \frac{1}{4} \text{ volt}$

R2 = 1.4 ohms 10 watt

R3 = 1.8 ohms 10 watt

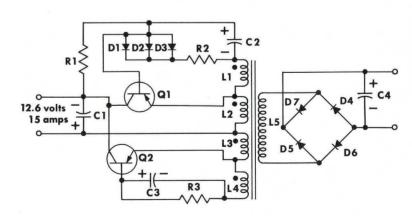
 $C1 = 500 \,\mu\text{f}$ 20 volt (must not be omitted)

C2, C3 = $20 \mu f 6 \text{ volt}$

Frequency about 1 kc.

Core-type 50017-2a Magnetics, Inc.

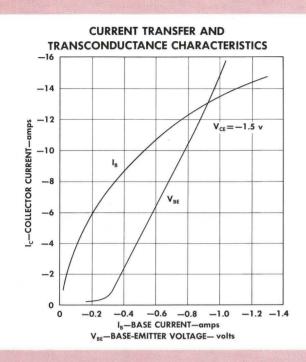
DC-TO-DC POWER CONVERTER 180-WATT OUTPUT AT 95% EFFICIENCY

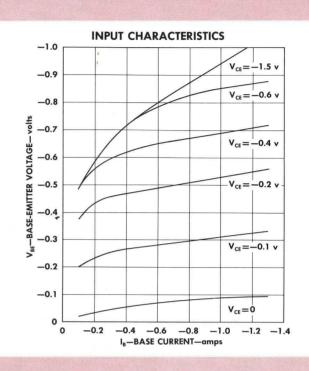


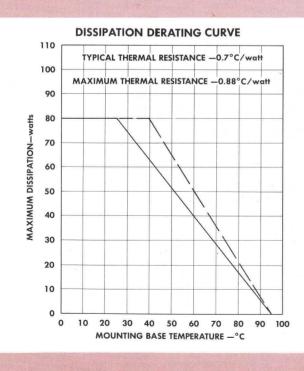
TEXAS INSTRUMENTS

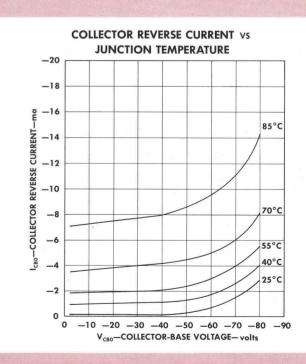
INCORPORATED

SEMICONDUCTOR-COMPONENTS DIVISION POST OFFICE BOX 312 - 13500 N. CENTRAL EXPRESSWAY Dallas, Texas TO SUPPLY THE BEST PRODUCTS POSSIBLE, TEXAS INSTRUMENTS RESERVES THE RIGHT TO MAKE CHANGES AT ANY TIME IN ORDER TO IMPROVE DESIGN.











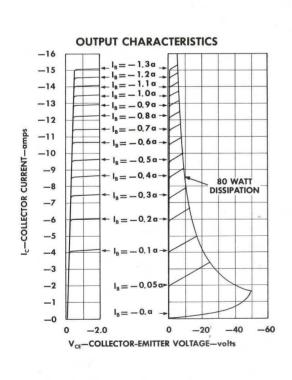
TYPES 2N512, 2N512A, 2N512B

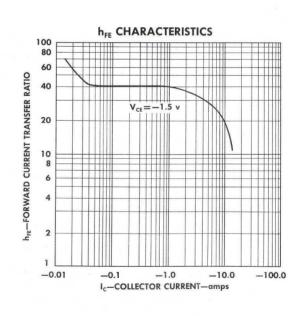
TYPICAL CHARACTERISTICS

design characteristics at 25°C

type	symbol	parameter	test conditions	min	design center	max	unit
2N512	BV _{CBO}		$I_C = -5$ ma, $I_E = 0$	-40	_	_	٧
0115101	I _{CBO}	Collector Reverse Current	$V_{CBO} = -20 \text{ v, } I_E = 0$	-	-0.2	-2.0	ma
2N512A			$I_C = -5$ ma, $I_E = 0$	-60	_	_	٧
2N512B	I _{CBO} BV _{CBO}	Collector Reverse Current Collector-to-Base	$V_{CB}=-30$ v, $I_E=0$	-	-0.2	-2.0	ma
ZNJIZD	ICBO		$I_C=-5$ ma, $I_E=0$	-80	-	=	٧
AII	I _{CBO}	Current Collector Reverse	$V_{CB} = -40 \text{ v, } I_E = 0$	-	-0.2	-2.0	ma
All	BV _{EBO}	Current Emitter-to-Base	$V_{CB} = -2 \text{ v, } I_E = 0$	-	-0.14	-	ma
All	I _{EBO}		$I_E = -5$ ma, $I_C = 0$	-30	-	_	V
All	I _B	Current Base Current	$V_{EB} = -15 \text{ v, } I_{C} = 0$ $V_{CE} = -1.5 \text{ v, } I_{C} = -3.7 \text{a}$	_	-0.25 -120.	200 .	ma ma
All	V _{BE}	Base Voltage	$V_{CE} = -1.5 \text{ v, } I_{C} = -15 \text{ a}$ $V_{CE} = -1.5 \text{ v, } I_{C} = -3.7 \text{ a}$	_	-1.2 -0.4	-1.4 -	a V
All	V _{CE} (SAT)	Collector-to-Emitter	$V_{CE} = -1.5 \text{ v, } I_{C} = -15a$	_	-1.0	-1.5	٧
All	fαe	Common-Emitter	$I_{C} = -15a, I_{B} - 2.25a$	-	-0.38	— 0.75	V
		Frequency Cutoff	$V_{CE} = -6 \text{ v, } I_C - 1a$		7.0		kc

TYPICAL CHARACTERISTICS — COMMON EMITTER





TEXAS INSTRUMENTS

INCORPORATED